

Abstract Submitted  
for the MAR06 Meeting of  
The American Physical Society

**Calculation of the Phonon Lifetime of Photoexcited Bismuth<sup>1</sup>**

EAMONN MURRAY, Department of Physics and Tyndall National Institute, University College, Cork, Ireland, DAVID PRENDERGAST<sup>2</sup>, TADASHI OGITSU, Lawrence Livermore National Laboratory, STEPHEN FAHY, Department of Physics and Tyndall National Institute, University College, Cork, Ireland — Phonon lifetimes of the zone-center longitudinal optical phonon in bismuth are calculated with respect to the fraction of valence band electrons excited into the conduction bands. Second order density-functional perturbation theory (DFPT), combined with the frozen phonon technique, is used to calculate the third-order anharmonic couplings between phonons. Calculations on the photoexcited system are performed by constraining the occupations of the valence and conduction bands, giving a certain excited electron-hole plasma density. It is found that the calculated decrease in the phonon lifetime with excitation is due both to the reduction of the phonon frequency and an increase in the coupling to other phonons.

<sup>1</sup>Supported by the Irish Research Council for Science, Engineering and Technology and SFI; and performed under the auspices of the U.S. Department of Energy by University of California Lawrence Livermore National Laboratory under contract No. W-7405-Eng-48.

<sup>2</sup>Present address: Department of Physics, University of California, Berkeley

Eamonn Murray  
Department of Physics and Tyndall National Institute, University College, Cork, Ireland

Date submitted: 16 Jan 2006

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